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an active matrix circuit including at least one thin film transistor formed over a first surface of said resulating substrate;

a driving circuit including at least another one thin film transistor for driving the active matrix circuit formed over said first surface of the insulating substrate;

a counter substrate facing the first surface of said insulating substrate with a liquid crystal material disposed therebetween, wherein said insulating substrate extends beyond at least one side edge of the counter substrate so as to provide an extended portion; and

at least one semiconductor integrated circuit chip disposed over said first surface of the extended portion of the insulating substrate and operationally connected with the driving [means] circuit,

wherein said at least one thin film transistor and said at least another one thin film transistor are formed from a common semiconductor film formed over the first surface of the insulating substrate.

(Four Times Amended) A liquid crystal display device comprising:

an insulating substrate;

an active matrix circuit including at least one thin film transistor;

a driving circuit including at least another one thin film transistor for driving the active matrix circuit; and

a control circuit for controlling the driving circuit, the control circuit being operationally connected with the driving circuit,

wherein the active matrix circuit, driving circuit and the control circuit are formed on the insulating substrate and wherein the control [means] circuit has at least one semiconductor integrated circuit chip, and

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